



# SGM2268

## 0.4Ω Ultra Low ON-Resistance, Dual, SPDT Analog Switch

### GENERAL DESCRIPTION

The SGM2268 is a dual single-pole/double-throw (SPDT) analog switch that is designed to operate from a single +1.8V to +4.2V power supply. Targeted applications include battery powered equipment that benefit from ultra low on-resistance (0.4Ω) and fast switching speeds.

SGM2268 features guaranteed on-resistance matching (0.04Ω TYP) between switches and guaranteed on-resistance flatness over the signal range (0.08Ω TYP), as well as high off-isolation and low crosstalk. This ensures excellent linearity and low distortion when switching audio signals.

The SGM2268 is a committed dual single-pole/double-throw (SPDT) that consist of two normally open (NO) and two normally close (NC) switches. This configuration can be used as a dual 2-to-1 multiplexer.

SGM2268 is available in Pb-free WQFN-10 package.

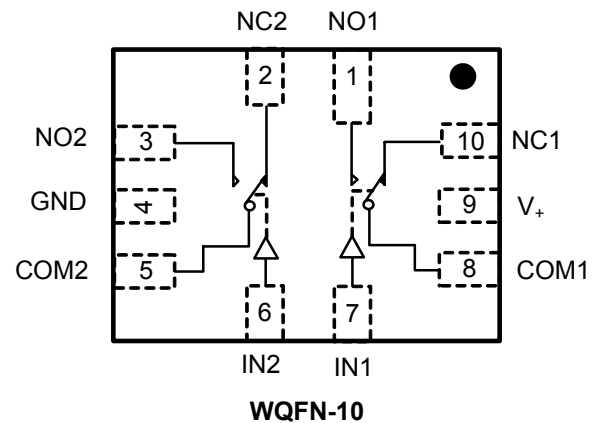
### APPLICATIONS

- Portable Instrumentation
- Battery-Operated Equipment
- Computer Peripherals
- Speaker and Earphone Switching
- Medical Equipment
- Audio and Video Switching

### FEATURES

- **Voltage Operation:** +1.8V to +4.2V
- **Ultra Low On-Resistance:** 0.4Ω (TYP) at +4.2V
- **On-Resistance Matching :** 0.04Ω (TYP)
- **On-Resistance Flatness:** 0.08Ω (TYP)
- **-3dB Bandwidth:** 40MHz
- **High Off-Isolation:** -78dB at 100kHz
- **Low Crosstalk:** -103dB at 100kHz
- **Rail-to-Rail Input and Output Operation**
- **TTL/CMOS Compatible**
- **Break-Before-Make Switching**
- **Extended Industrial Temperature Range:** -40°C to +85°C
- **Lead (Pb) Free WQFN-10 Package**

### PIN CONFIGURATION (TOP VIEW)



### FUNCTION TABLE

LOGIC	NO	NC
0	OFF	ON
1	ON	OFF

Switches Shown For Logic "0" Input.

**ORDERING INFORMATION**

MODEL	PIN-PACKAGE	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKAGE OPTION
SGM2268	WQFN-10	-40°C to +85°C	SGM2268YWQ10/TR	2268	Tape and Reel, 3000

**ABSOLUTE MAXIMUM RATINGS**

V <sub>+</sub> , IN to GND.....	0V to 4.6V	Storage Temperature.....	-65°C to +150°C
Analog, Digital voltage range <sup>(1)</sup> .....	-0.3V to (V <sub>+</sub> ) + 0.3V	Lead Temperature (soldering, 10s).....	260°C
Continuous Current NO, NC, or COM.....	±250mA	ESD Susceptibility	
Peak Current NO, NC, or COM.....	±350mA	HBM.....	4000V
Operating Temperature Range.....	-40°C to +85°C	MM.....	400V
Junction Temperature.....	150°C		

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note1: Signals on NC, NO, or COM or IN exceeding V<sub>+</sub> will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

**CAUTION**

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

**PIN DESCRIPTION**

WQFN-10	NAME	FUNCTION
9	V <sub>+</sub>	Power supply
4	GND	Ground
7,6	IN1, IN2	Digital control pin to connect the COM terminal to the NO or NC terminals
8,5	COM1, COM2	Common terminal
1,3	NO1, NO2	Normally-open terminal
10,2	NC1, NC2	Normally-closed terminal

Note: NO, NC and COM terminals may be an input or output.

**ELECTRICAL CHARACTERISTICS**

( $V_+$  = +4.2V, GND = 0V,  $V_{IH}$  = +1.6V,  $V_{IL}$  = +0.6V,  $T_A$  = -40°C to + 85°C. Typical values are at  $V_+$  = +4.2V,  $T_A$  = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
<b>ANALOG SWITCH</b>							
Analog Signal Range	$V_{NO}, V_{NC}, V_{COM}$		-40°C to +85°C	0		$V_+$	V
On-Resistance	$R_{ON}$	$V_+$ = 4.2V, $V_{NO}, V_{NC}$ or $V_{COM}$ = 1V, $I_{COM}$ = -100mA, Test Circuit 1	+25°C		0.4	0.65	Ω
			-40°C to +85°C			0.75	Ω
On-Resistance Match Between Channels	$\Delta R_{ON}$	$V_+$ = 4.2V, $V_{NO}, V_{NC}$ or $V_{COM}$ = 1V, $I_{COM}$ = -100mA, Test Circuit 1	+25°C		0.04	0.15	Ω
			-40°C to +85°C			0.2	Ω
On-Resistance Flatness	$R_{FLAT(ON)}$	$V_+$ = 4.2V, $V_{NO}, V_{NC}$ or $V_{COM}$ = 1V, 2.5V, $I_{COM}$ = -100mA, Test Circuit 1	+25°C		0.08	0.12	Ω
			-40°C to +85°C			0.2	Ω
Source OFF Leakage Current	$I_{NC(OFF)}, I_{NO(OFF)}$	$V_+$ = 4.2V, $V_{NO}$ or $V_{NC}$ = 3.3V/ 0.3V, $V_{COM}$ = 0.3V/ 3.3V	-40°C to +85°C			1	μA
Channel ON Leakage Current	$I_{NC(ON)}, I_{NO(ON)}, I_{COM(ON)}$	$V_+$ = 4.2V, $V_{COM}$ = 0.3V/ 3.3V, $V_{NO}$ or $V_{NC}$ = 0.3V/ 3.3V, or floating	-40°C to +85°C			1	μA
<b>DIGITAL INPUTS</b>							
Input High Voltage	$V_{INH}$		-40°C to +85°C	1.6			V
Input Low Voltage	$V_{INL}$		-40°C to +85°C			0.5	V
Input Leakage Current	$I_{IN}$	$V_+$ = 4.2V, $V_{IN}$ = 0V or 4.2V	-40°C to +85°C			1	μA
<b>DYNAMIC CHARACTERISTICS</b>							
Turn-On Time	$t_{ON}$	$V_{IN}$ = 2.1V to 0V, $R_L$ = 50Ω, $C_L$ = 35pF, $V_{NO1}$ or $V_{NC1}$ = $V_{NO2}$ or $V_{NC2}$ = 2.1V, Test Circuit2	+25°C		88		ns
Turn-Off Time	$t_{OFF}$	$V_{IN}$ = 2.1V to 0V, $R_L$ = 50Ω, $C_L$ = 35pF, $V_{NO1}$ or $V_{NC1}$ = $V_{NO2}$ or $V_{NC2}$ = 2.1V, Test Circuit2	+25°C		16		ns
Break-Before-Make Time Delay	$t_D$	$V_{IN}$ = 2.1V to 0V, $R_L$ = 50Ω, $C_L$ = 35pF, $V_{NO1}$ or $V_{NC1}$ = $V_{NO2}$ or $V_{NC2}$ = 2.1V, Test Circuit3	+25°C		6.0		ns
Off Isolation	$O_{ISO}$	$V_{BIAS}$ = 2.1V, Signal = 0dBm, Test Circuit4	100kHz	+25°C		-78	dB
			1MHz	+25°C		-58	dB
Channel-to-Channel Crosstalk	$X_{TALK}$	$V_{BIAS}$ = 2.1V, Signal = 0dBm, Test Circuit5	100kHz	+25°C		-103	dB
			1MHz	+25°C		-90	dB
-3dB Bandwidth	BW	$V_{BIAS}$ = 2.1V, Signal = 0dBm, Test Circuit6	+25°C		40.0		MHz
Charge Injection Select Input to Common I/O	Q	$V_G$ = 0V, $R_s$ = 0Ω, $C_L$ = 1.0nF, Test Circuit7	+25°C		4.0		pC
Channel ON Capacitance	$C_{ON}$		+25°C		106		pF
<b>POWER REQUIREMENTS</b>							
Power Supply Range	$V_+$		-40°C to +85°C	1.8		4.2	V
Power Supply Current	$I_+$	$V_+$ = 4.2V, $V_{IN}$ = 0V or $V_+$	-40°C to +85°C			1	μA

Specifications subject to changes without notice.

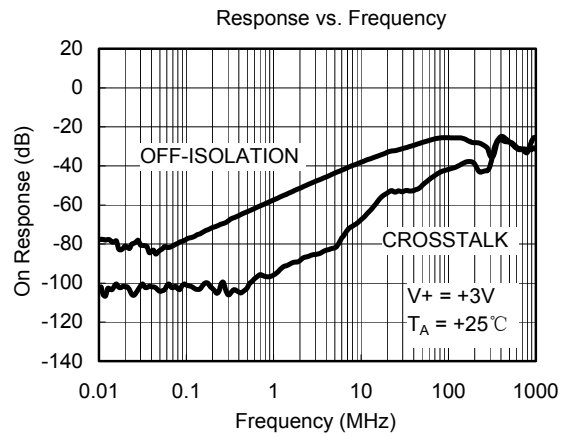
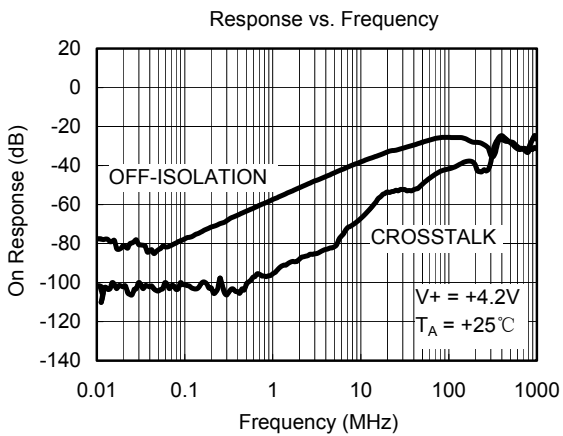
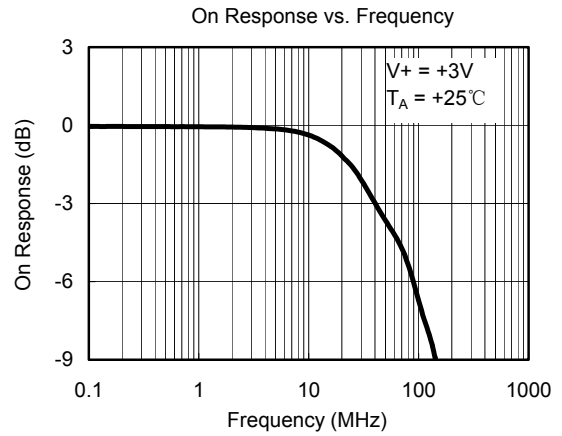
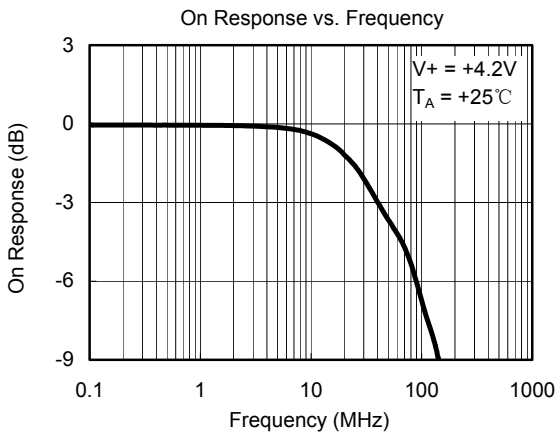
**ELECTRICAL CHARACTERISTICS**

( $V_+ = +2.7V$  to  $+3.6V$ ,  $GND = 0V$ ,  $V_{IH} = +1.6V$ ,  $V_{IL} = +0.4V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ . Typical values are at  $V_+ = +3.0V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

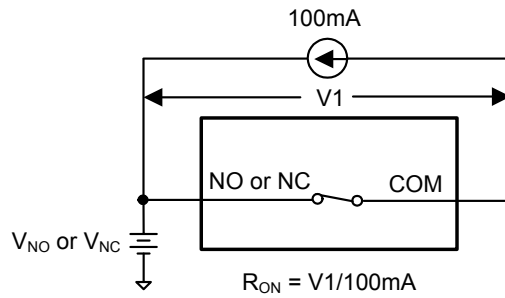
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
<b>ANALOG SWITCH</b>							
Analog Signal Range	$V_{NO}, V_{NC}, V_{COM}$		$-40^\circ C$ to $+85^\circ C$	0		$V_+$	V
On-Resistance	$R_{ON}$	$V_+ = 2.7V, V_{NO}, V_{NC}$ or $V_{COM} = 1V,$ $I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		0.5	0.7	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			0.8	$\Omega$
On-Resistance Match Between Channels	$\Delta R_{ON}$	$V_+ = 2.7V, V_{NO}, V_{NC}$ or $V_{COM} = 1V,$ $I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		0.03	0.15	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			0.2	$\Omega$
On-Resistance Flatness	$R_{FLAT(ON)}$	$V_+ = 2.7V, V_{NO}, V_{NC}$ or $V_{COM} = 1V, 2.5V,$ $I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		0.1	0.18	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			0.2	$\Omega$
Source OFF Leakage Current	$I_{NC(OFF)}, I_{NO(OFF)}$	$V_+ = 3.6V, V_{NO}$ or $V_{NC} = 3.3V / 0.3V,$ $V_{COM} = 0.3V / 3.3V$	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
Channel ON Leakage Current	$I_{NC(ON)}, I_{NO(ON)},$ $I_{COM(ON)}$	$V_+ = 3.6V, V_{COM} = 0.3V / 3.3V,$ $V_{NO}$ or $V_{NC} = 0.3V / 3.3V$ , or floating	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
<b>DIGITAL INPUTS</b>							
Input High Voltage	$V_{INH}$		$-40^\circ C$ to $+85^\circ C$	1.5			V
Input Low Voltage	$V_{INL}$		$-40^\circ C$ to $+85^\circ C$			0.4	V
Input Leakage Current	$I_{IN}$	$V_+ = 2.7V, V_{IN} = 0V$ or $2.7V$	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
<b>DYNAMIC CHARACTERISTICS</b>							
Turn-On Time	$t_{ON}$	$V_{IN} = 1.5V$ to $0V, R_L = 50\Omega, C_L = 35pF,$ $V_{NO1}$ or $V_{NC1} = V_{NO2}$ or $V_{NC2} = 1.5V,$ Test Circuit2	$+25^\circ C$		100		ns
Turn-Off Time	$t_{OFF}$	$V_{IN} = 1.5V$ to $0V, R_L = 50\Omega, C_L = 35pF,$ $V_{NO1}$ or $V_{NC1} = V_{NO2}$ or $V_{NC2} = 1.5V,$ Test Circuit2	$+25^\circ C$		20		ns
Break-Before-Make Time Delay	$t_D$	$V_{IN} = 1.5V$ to $0V, R_L = 50\Omega, C_L = 35pF,$ $V_{NO1}$ or $V_{NC1} = V_{NO2}$ or $V_{NC2} = 1.5V,$ Test Circuit3	$+25^\circ C$		9.2		ns
Off Isolation	$O_{ISO}$	$V_{BIAS} = 2.1V, \text{Signal} = 0dBm,$ Test Circuit4	100kHz	$+25^\circ C$		-78	dB
			1MHz	$+25^\circ C$		-58	dB
Channel-to-Channel Crosstalk	$X_{TALK}$	$V_{BIAS} = 2.1V, \text{Signal} = 0dBm,$ Test Circuit5	100kHz	$+25^\circ C$		-103	dB
			1MHz	$+25^\circ C$		-90	dB
-3dB Bandwidth	BW	$V_{BIAS} = 2.1V, \text{Signal} = 0dBm,$ Test Circuit6	$+25^\circ C$		40		MHz
Charge Injection Select Input to Common I/O	Q	$V_G = 0V, R_s = 0\Omega, C_L = 1.0nF,$ Test Circuit7	$+25^\circ C$		3.0		pC
Channel ON Capacitance	$C_{ON}$		$+25^\circ C$		106		pF

Specifications subject to changes without notice.

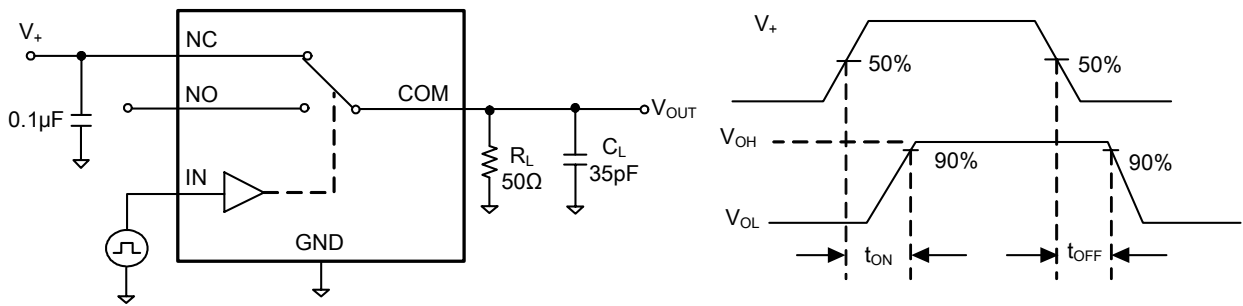
TYPICAL PERFORMANCE CHARACTERISTICS



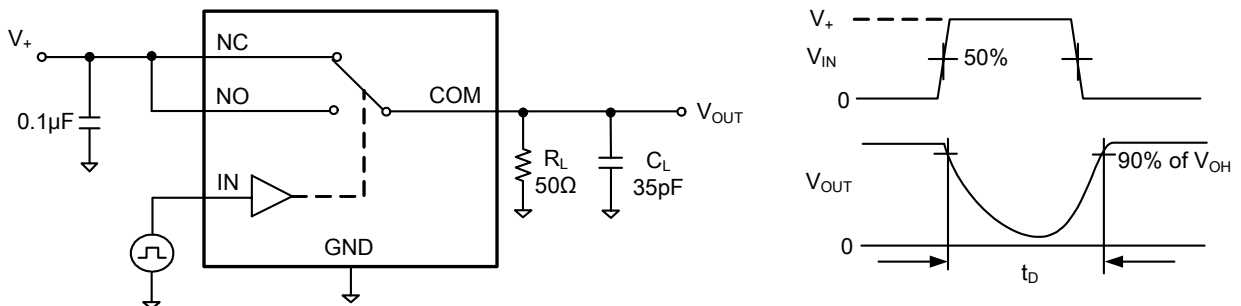
TEST CIRCUITS



Test Circuit 1. On Resistance

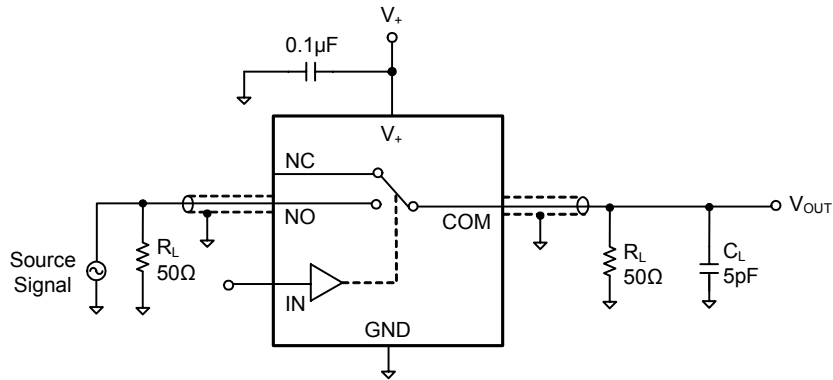


Test Circuit 2. Switching Times ( $t_{ON}$ ,  $t_{OFF}$ )

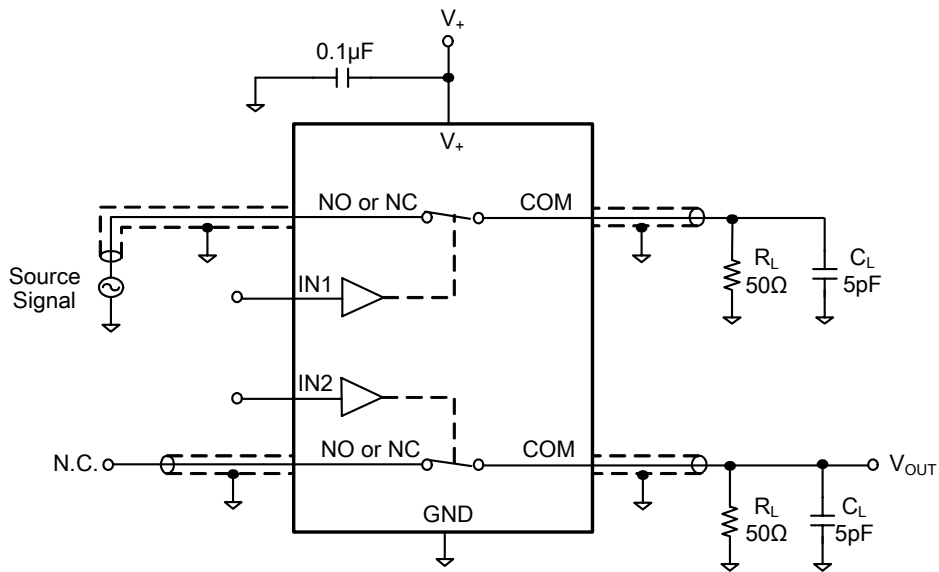


Test Circuit 3. Break-Before-Make Time ( $t_D$ )

TEST CIRCUITS (Cont.)



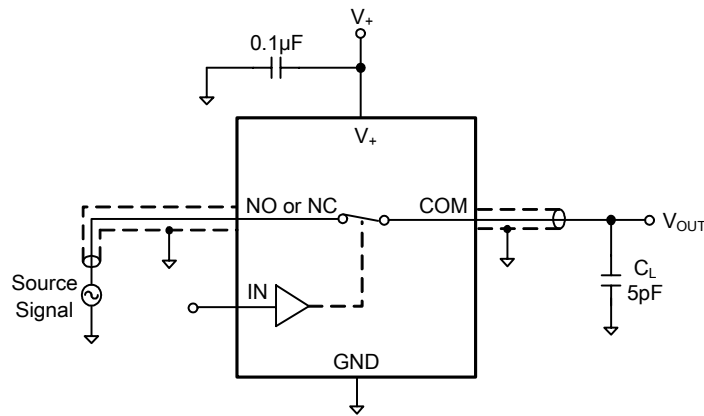
Test Circuit 4. Off Isolation



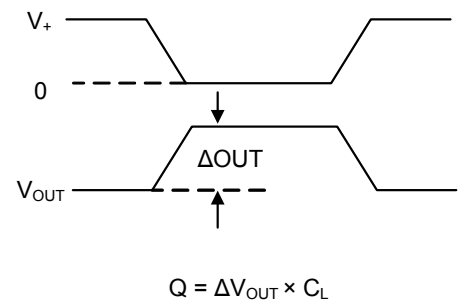
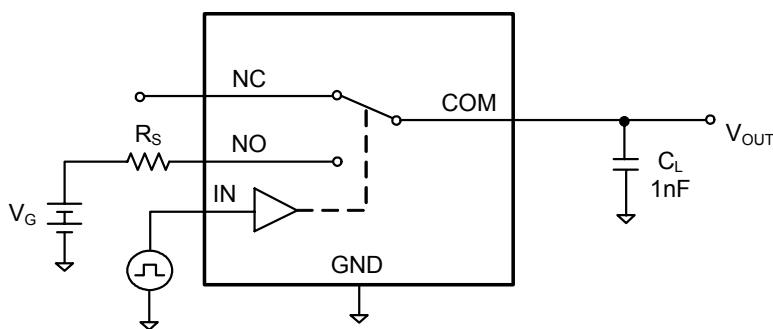
$$\text{Channel To Channel Crosstalk} = -20 \times \log \frac{V_{NO \text{ or } V_{NC}}}{V_{OUT}}$$

Test Circuit 5. Channel-to-Channel Crosstalk

TEST CIRCUITS (Cont.)



Test Circuit 6. -3dB Bandwidth

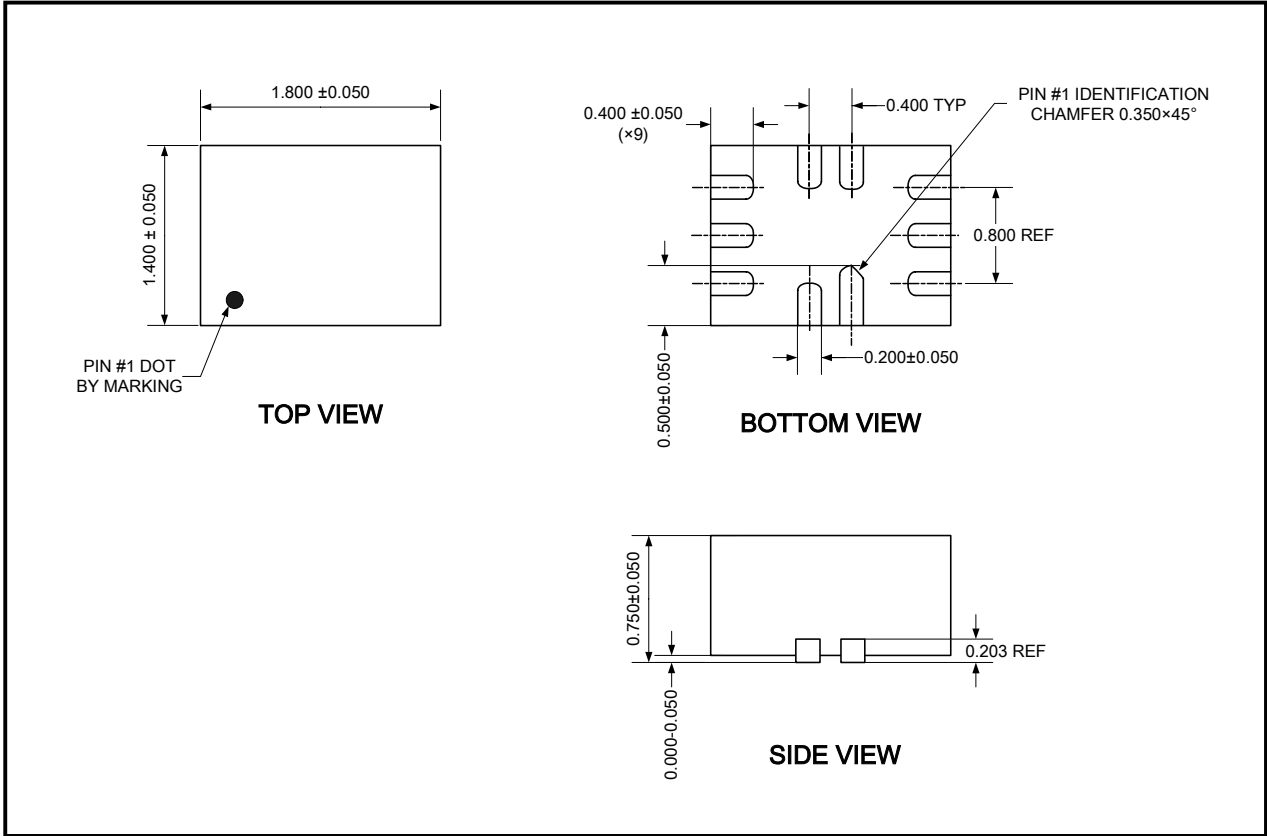


Test Circuit 7. Charge Injection (Q)



PACKAGE OUTLINE DIMENSIONS

WQFN-10



Note: All linear dimensions are in millimeters.

12/2008 REV. A. 1

SGMICRO is dedicated to provide high quality and high performance analog IC products to customers. All SGMICRO products meet the highest industry standards with strict and comprehensive test and quality control systems to achieve world-class consistency and reliability.

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